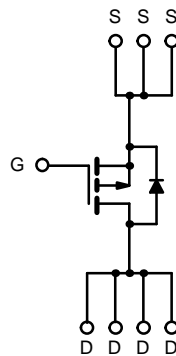
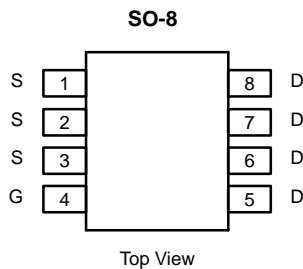


P-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY		
V_{DS} (V)	$r_{DS(on)}$ (Ω)	I_D (A)
-30	0.055 @ $V_{GS} = -10$ V	± 5.1
	0.07 @ $V_{GS} = -6$ V	± 4.6
	0.105 @ $V_{GS} = -4.5$ V	± 3.6



ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)			
Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	-30	V
Gate-Source Voltage	V_{GS}	± 20	
Continuous Drain Current ($T_J = 150^\circ\text{C}$) ^a	I_D	$T_A = 25^\circ\text{C}$	A
		$T_A = 70^\circ\text{C}$	
Pulsed Drain Current	I_{DM}	± 20	
Continuous Source Current (Diode Conduction) ^a	I_S	-2.6	
Maximum Power Dissipation ^a	P_D	$T_A = 25^\circ\text{C}$	W
		$T_A = 70^\circ\text{C}$	
Operating Junction and Storage Temperature Range	T_J, T_{stg}	-55 to 150	$^\circ\text{C}$

THERMAL RESISTANCE RATINGS			
Parameter	Symbol	Limit	Unit
Maximum Junction-to-Ambient ^a	R_{thJA}	50	$^\circ\text{C/W}$

Notes

a. Surface Mounted on FR4 Board, $t \leq 10$ sec.

For SPICE model information via the Worldwide Web: <http://www.vishay.com/www/product/spice.htm>



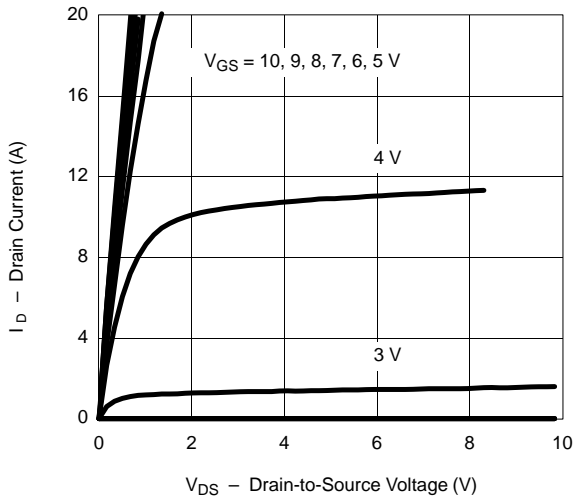
SPECIFICATIONS (T _J = 25 °C UNLESS OTHERWISE NOTED)						
Parameter	Symbol	Test Condition	Min	Typ ^a	Max	Unit
Static						
Gate Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = -250 μA	-1.0			V
Gate-Body Leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ±20 V			±100	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = -24 V, V _{GS} = 0 V			-1	μA
		V _{DS} = -15 V, V _{GS} = 0 V, T _J = 70 °C			-5	
On-State Drain Current ^b	I _{D(on)}	V _{DS} ≤ -10 V, V _{GS} = -10 V	-20			A
		V _{DS} ≤ -5 V, V _{GS} = -4.5 V	-5			
Drain-Source On-State Resistance ^b	r _{DS(on)}	V _{GS} = -10 V, I _D = -4.6 A		0.037	0.055	Ω
		V _{GS} = -6 V, I _D = -4.1 A		0.047	0.07	
		V _{GS} = -4.5 V, I _D = -2.0 A		0.060	0.105	
Forward Transconductance ^b	g _{fs}	V _{DS} = -15 V, I _D = -4.6 A		9.0		S
Diode Forward Voltage ^b	V _{SD}	I _S = -2.6 A, V _{GS} = 0 V		-0.88	-1.2	V
Dynamic^a						
Total Gate Charge	Q _g	V _{DS} = -15 V, V _{GS} = -10 V, I _D = -4.6 A		27	40	nC
Gate-Source Charge	Q _{gs}			4		
Gate-Drain Charge	Q _{gd}			6.3		
Turn-On Delay Time	t _{d(on)}	V _{DD} = -15 V, R _L = 15 Ω I _D ≅ -1 A, V _{GEN} = -10 V, R _G = 6 Ω		14	30	ns
Rise Time	t _r			13	60	
Turn-Off Delay Time	t _{d(off)}			58	120	
Fall Time	t _f			21	100	
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 2.6 A, di/dt = 100 A/μs		65	100	

Notes

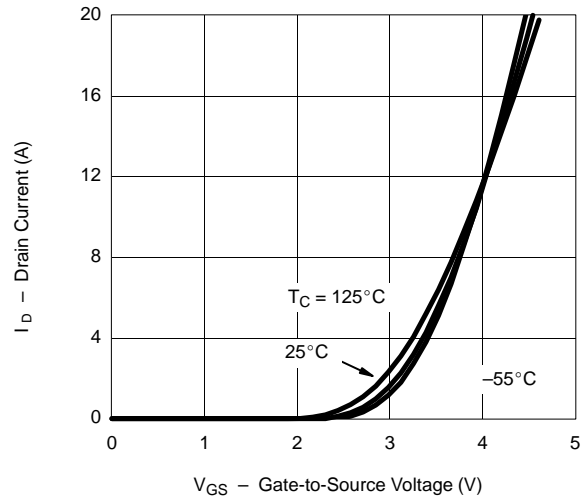
- a. Guaranteed by design, not subject to production testing.
- b. Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2%.

TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)

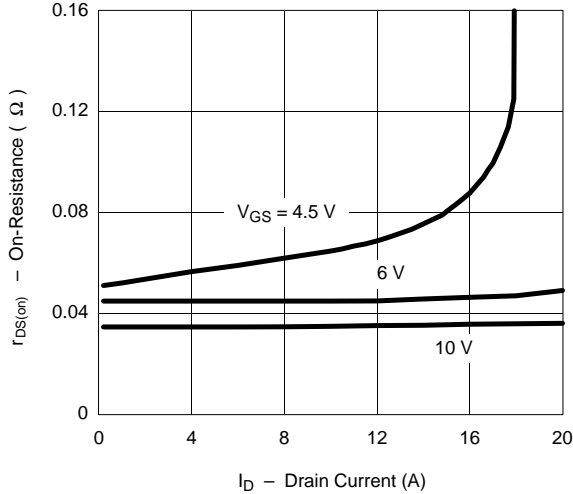
Output Characteristics



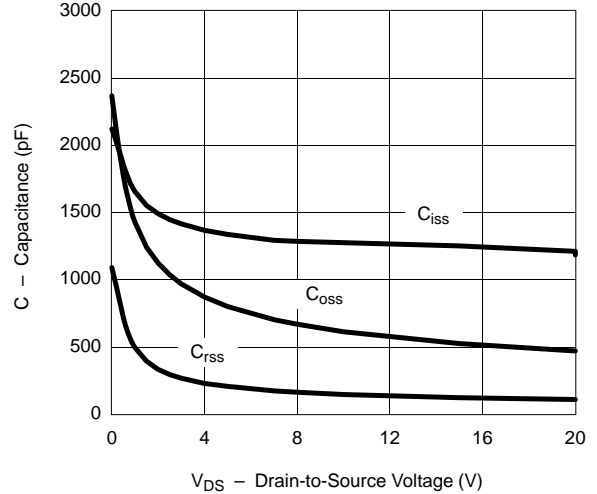
Transfer Characteristics



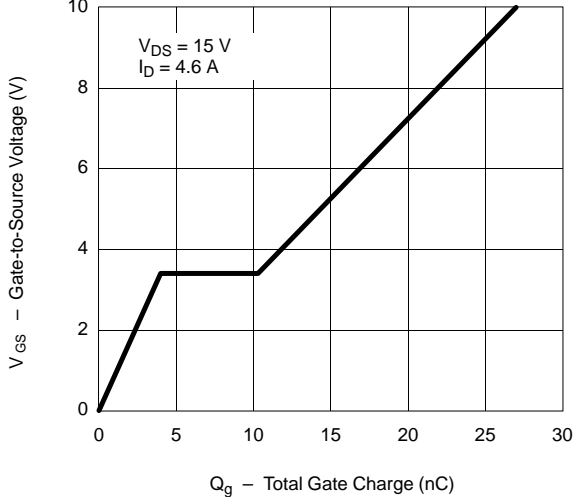
On-Resistance vs. Drain Current



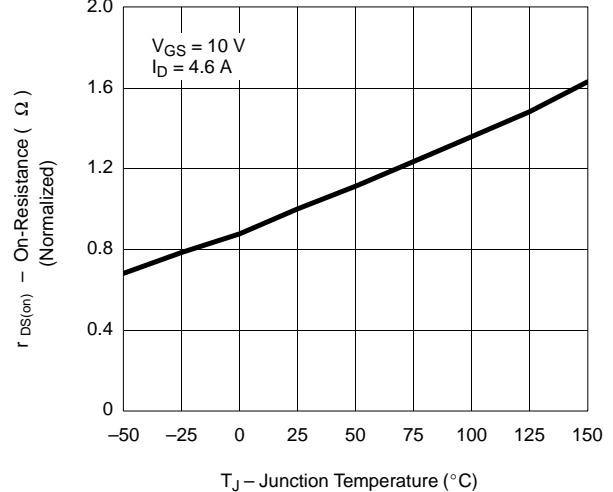
Capacitance



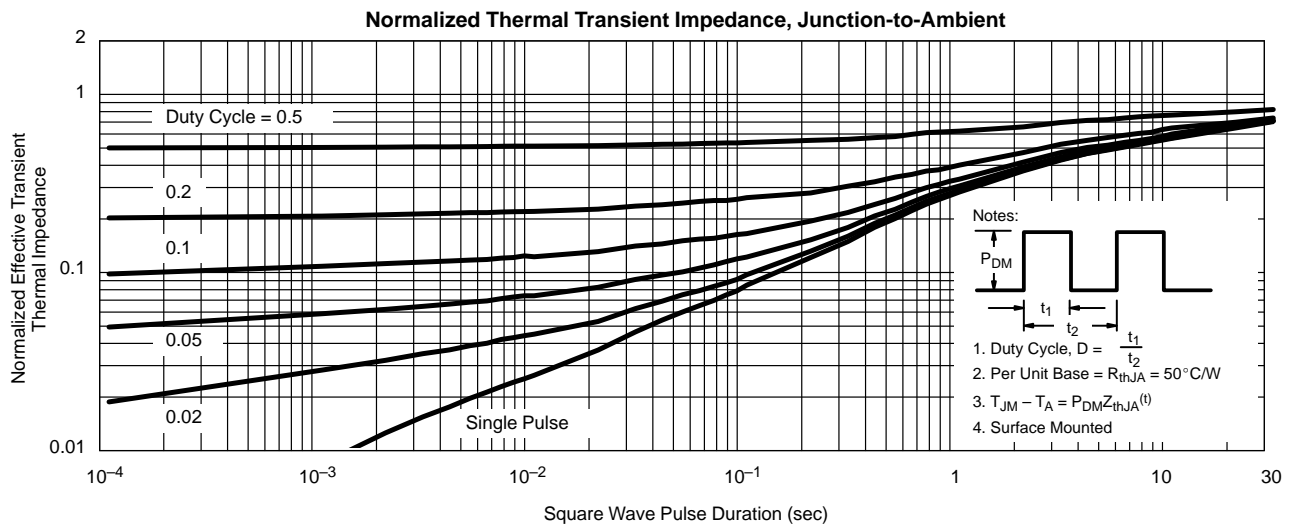
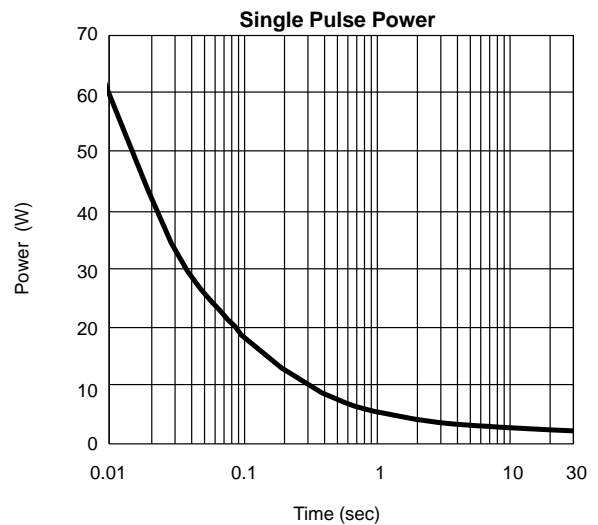
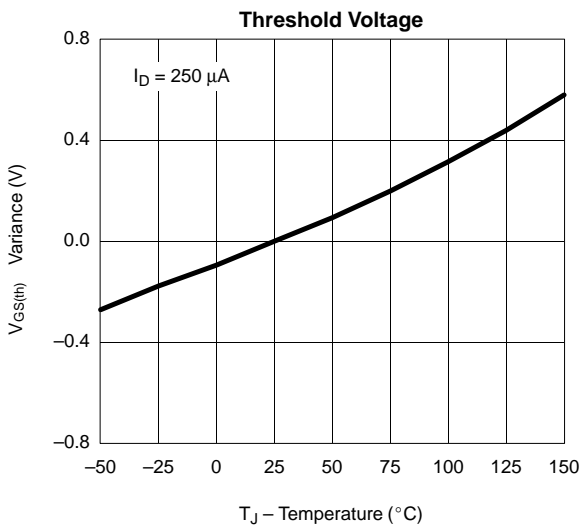
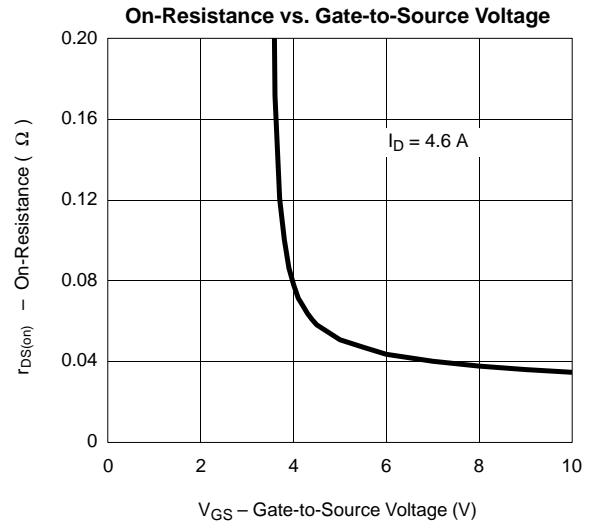
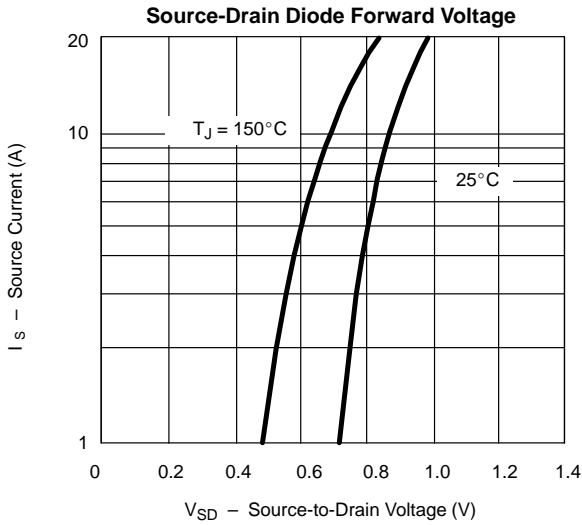
Gate Charge



On-Resistance vs. Junction Temperature



TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)





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